

S G S-THOMSON

**SENSITIVE GATE TRIACS**

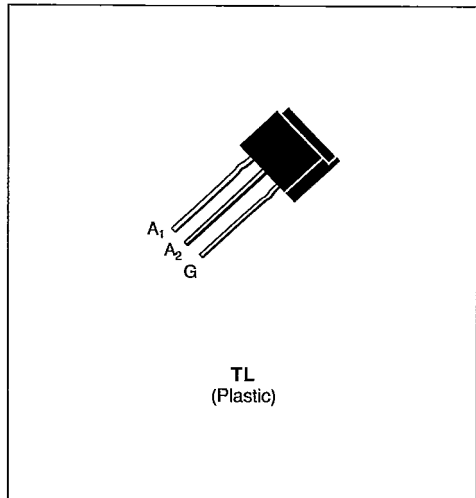
- GLASS PASSIVATED CHIP
- HIGH SURGE CURRENT

**DESCRIPTION**

Low power triacs suited for 50 and 60 Hz up to 380 V<sub>RMS</sub>.

**APPLICATIONS**

- CONTROL SPEED FOR LITTLE MOTORS ;  
ELECTRIC PUMP OR VENTILATOR, SEWING MACHINE
- RELAY, DETECTOR, ALARM SYSTEM
- ELECTRONIC STARTER FOR LAMP
- HIGH POWER TRIAC DRIVER


**ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit	
$I_{T(RMS)}$	RMS on-state Current (360° conduction angle) $T_J = 40\text{ }^\circ\text{C}$	1	A	
$I_{T(RMS)}$	RMS on-state Current on Printed Circuit (360° conduction angle) $T_a = 25\text{ }^\circ\text{C}$	0.77	A	
$I_{TSM}$	Non Repetitive Surge Peak on-state Current ( $T_J$ initial = 25 °C - Half sine wave)	$t = 8.3\text{ ms}$	16	A
		$t = 10\text{ ms}$	15	
$I^2t$	$I^2t$ Value for Fusing $t = 10\text{ ms}$	1.125	A <sup>2</sup> s	
$di/dt$	Critical Rate of Rise of on-state Current (1) Repetitive	10	A/ $\mu$ s	
$T_{stg}$ $T_J$	Storage and Operating Junction Temperature Range	- 40 to 150 - 40 to 110	$^\circ\text{C}$ $^\circ\text{C}$	

Symbol	Parameter	TLC111A	TLC221A	TLC331A	TLC381A	Unit
$V_{DRM}$	Repetitive Peak off-state Voltage (2)	200	400	600	700	V

- (1)  $I_G = 250\text{ mA}$   $di/dt = 1\text{ A}/\mu\text{s}$   
 (2)  $T_J = 110\text{ }^\circ\text{C}$ .

**THERMAL RESISTANCES**

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to Ambient on Printed Circuit	75	$^\circ\text{C}/\text{W}$
$R_{th(j-l)}$	Junction-leads for 360° Conduction Angle ( $F = 50\text{ Hz}$ )	45	$^\circ\text{C}/\text{W}$

# GATE CHARACTERISTICS (maximum values)

SGS-THOMSON

$P_{GM} = 2 \text{ W}$  ( $t_p = 10 \mu\text{s}$ )

$I_{GM} = 1 \text{ A}$  ( $t_p = 10 \mu\text{s}$ )

$P_G(AV) = 0.1 \text{ W}$

$V_{GM} = 16 \text{ V}$  ( $t_p = 10 \mu\text{s}$ )

T-25-13

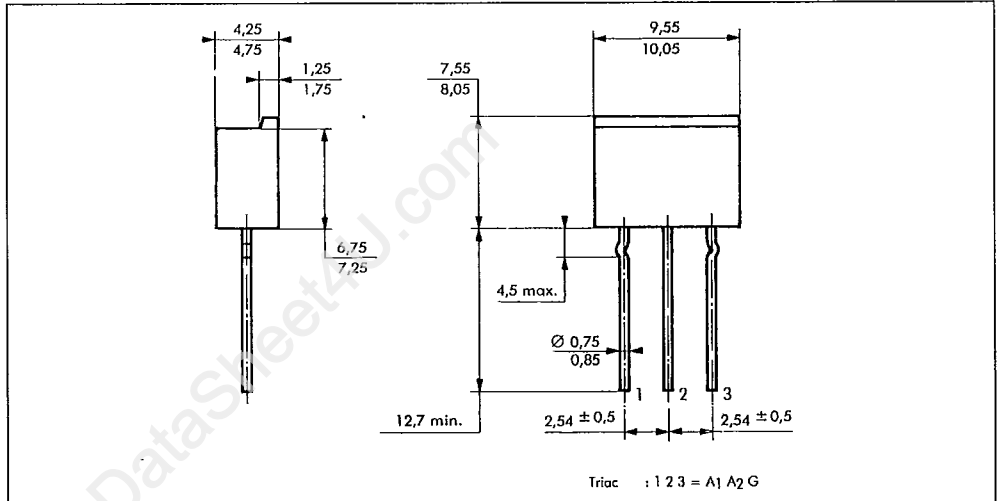
# ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions			Quadrants	Min.	Typ.	Max.	Unit
$I_{GT}$	$T_j = 25 \text{ }^\circ\text{C}$ Pulse Duration > 20 $\mu\text{s}$	$V_D = 12 \text{ V}$	$R_L = 33 \text{ } \Omega$	I-II-III			10	mA
				IV			25	
$V_{GT}$	$T_j = 25 \text{ }^\circ\text{C}$ Pulse Duration > 20 $\mu\text{s}$	$V_D = 12 \text{ V}$	$R_L = 33 \text{ } \Omega$	I-II-III-IV			1.5	V
$V_{GD}$	$T_j = 110 \text{ }^\circ\text{C}$	$V_D = V_{DRM}$	$R_L = 3.3 \text{ k}\Omega$	I-II-III-IV	0.2			V
$I_H^*$	$T_j = 25 \text{ }^\circ\text{C}$	$I_T = 100 \text{ mA}$	Gate Open				25	mA
$I_L$	$T_j = 25 \text{ }^\circ\text{C}$ Pulse Duration > 20 $\mu\text{s}$	$V_D = 12 \text{ V}$	$I_G = 50 \text{ mA}$	I-II-III-IV			25	mA
$V_{TM}^*$	$T_j = 25 \text{ }^\circ\text{C}$	$I_{TM} = 1.4 \text{ A}$	$t_p = 10 \text{ ms}$				1.8	V
$I_{DRM}^*$	$V_{DRM}$ Specified						0.01	mA
							0.75	
$dv/dt^*$	$T_j = 110 \text{ }^\circ\text{C}$ Linear Slope up to $V_D = 67 \% V_{DRM}$	Gate Open				20		V/ $\mu\text{s}$
$(dv/dt)_c^*$	$T_j = 40 \text{ }^\circ\text{C}$ $(di/dt)_c = 0.4 \text{ A/ms}$	$V_D = V_{DRM}$	$I_T = 1.4 \text{ A}$			5		V/ $\mu\text{s}$
$t_{gt}$	$T_j = 25 \text{ }^\circ\text{C}$ $I_G = 100 \text{ mA}$	$V_D = V_{DRM}$ $di_G/dt = 1 \text{ A}/\mu\text{s}$	$I_T = 1.4 \text{ A}$	I-II-III-IV		3		$\mu\text{s}$

\* For either polarity of electrode  $A_2$  voltage with reference to electrode  $A_1$ .

# PACKAGE MECHANICAL DATA

TL Plastic



Cooling method : by convection (method A)

Marking : type number

Weight : 0.8 g.

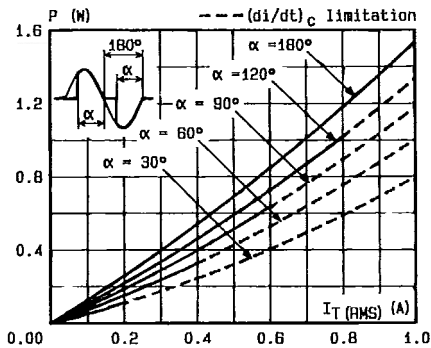


Fig.1 - Maximum mean power dissipation versus RMS on-state current ( $F = 60$  Hz).

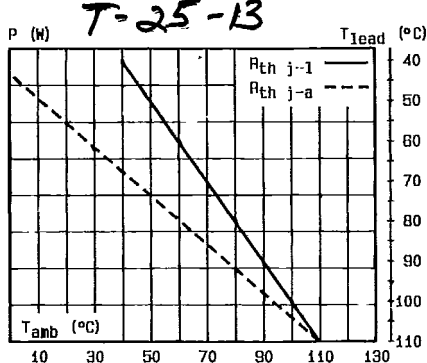


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{lead}$ ), resistances heatsink + contact.

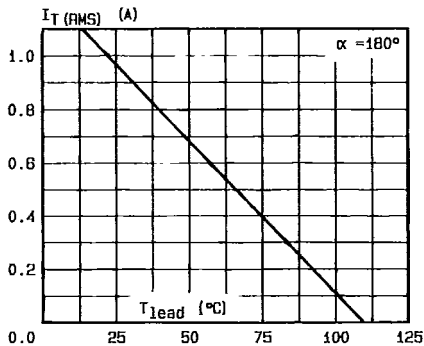


Fig.3 - RMS on-state current versus lead temperature.

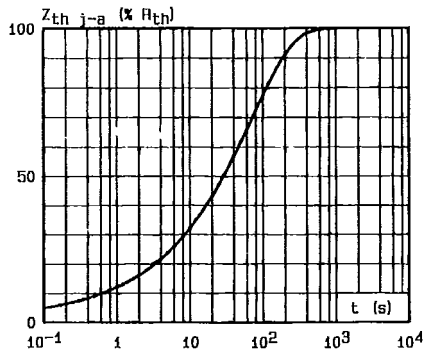


Fig.4 - Thermal transient impedance junction to ambient versus pulse duration.

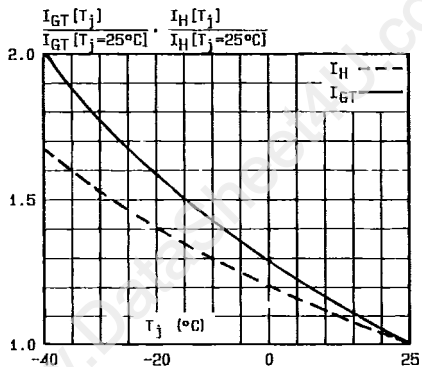


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

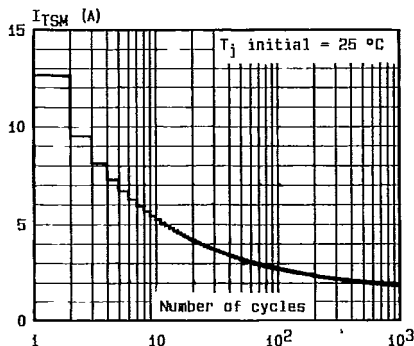


Fig.6 - Non repetitive surge peak on state current versus number of cycles.

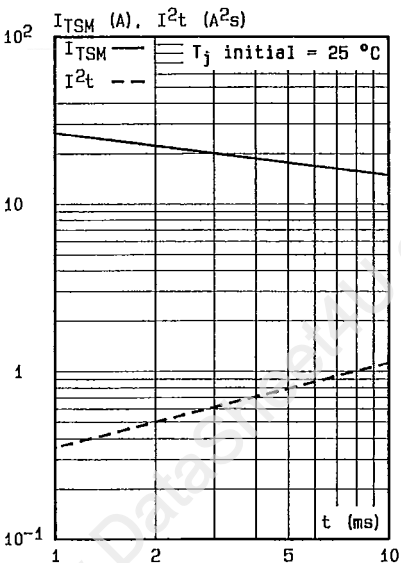


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

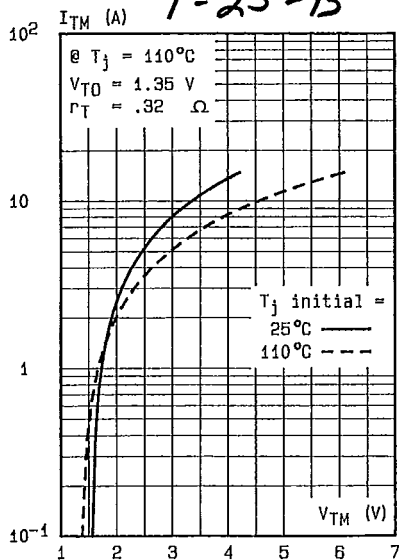


Fig.8 - On-state characteristics (maximum values).